

APT13005DI-G1 Datasheet



DiGi Electronics Part Number	APT13005DI-G1-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	APT13005DI-G1
Description	TRANS NPN 450V 4A TO251
Detailed Description	Bipolar (BJT) Transistor NPN 450 V 4 A 4MHz 25 W T hrough Hole TO-251

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
APT13005DI-G1	Diodes Incorporated
Series:	Product Status:
-	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
NPN	4 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
450 V	900mV @ 1A, 4A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
-	8 @ 2A, 5V
Power - Max:	Frequency - Transition:
25 W	4MHz
Operating Temperature:	Mounting Type:
-65°C ~ 150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-251-3 Short Leads, IPak, TO-251AA	TO-251
Base Product Number:	
APT13005	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Affected	EAR99
HTSUS:	
8541.29.0095	



PART OBSOLETE - CONTACT US



APT13005D

Features

- BV_{CEO} > 450V
- BV_{CES} > 700V
- BV_{EBO} > 9V
- I_C = 4A High Collector Current
- Integrated Anti-Parallel Diode to act as free-wheeling diode
- Anti-Saturation feature
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Applications

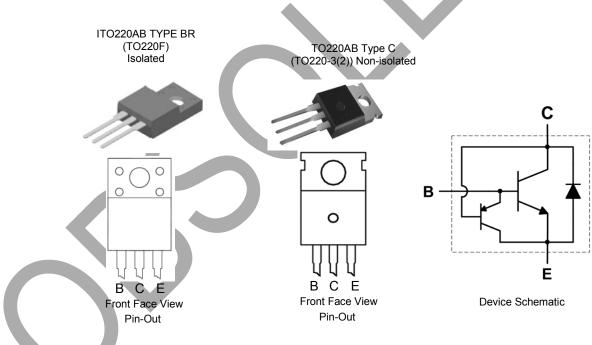
Low power AC-DC SMPS for:

- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED Lighting

450V NPN HIGH VOLTAGE POWER TRANSISTOR

Mechanical Data

- Case: ITO220AB TYPE BR (TO220F), TO220AB Type C
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Terminals: Finish Matte Tin Finish Leads, Solderable per MIL-STD-202, Method 208 ⁽²³⁾
- Weight: ITO220AB TYPE BR (TO220F): 1500mg (Approximate) TO220AB Type C : 2000mg (Approximate)



Ordering Information (Note 4)

Product	Package	Marking	Quantity
APT13005DTF-G1	ITO220AB TYPE BR (TO220F)	APT13005DTF-G1	1,000 per Box in Tubes
APT13005DT-G1	TO220AB Type C (TO220-3(2))	APT13005DT-G1	1,000 per Box in Tubes

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

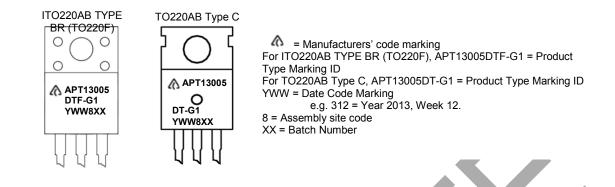
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CES}	700	V
Collector-Emitter Voltage	V _{CEO}	450	V
Emitter-Base Voltage	V _{EBO}	9	V
Collector Current	Ic	4	А
Peak Collector Current	I _{CM}	8	А
Base Current	Ι _Β	2	А
Peak Base Current	I _{BM}	4	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation $@T_C = +25^{\circ}C$	For ITO220AB TYPE BR (TO220F)	PD	28	W
	For TO220AB Type C		75	
Thermal Resistance, Junction to Case	For ITO220AB TYPE BR (TO220F)	R _{θJC}	4.5	°C/W
	For TO220AB Type C		1.67	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-65 to +150	°C

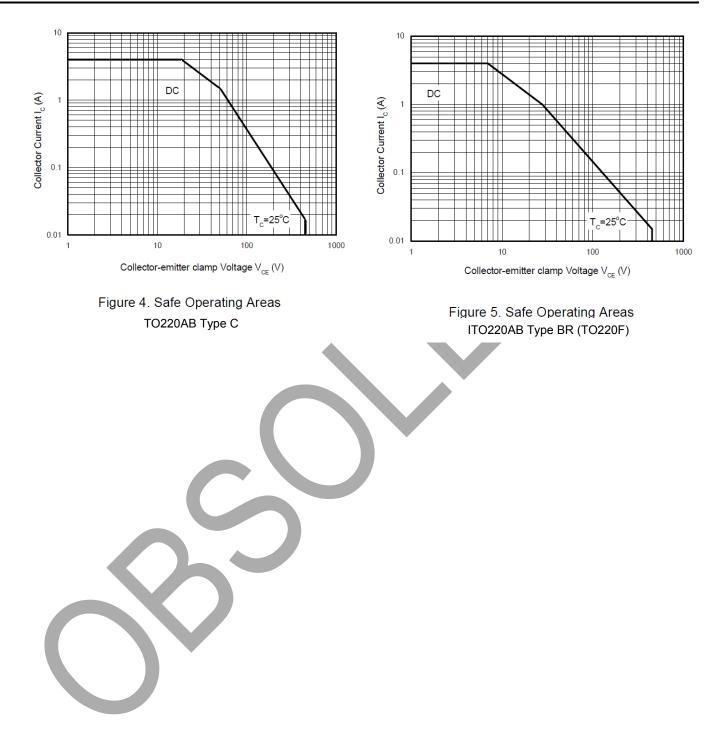
ESD Ratings (Note 5)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Note: 5. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Safe Operating Areas (@T_A = +25°C, unless otherwise specified.)



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

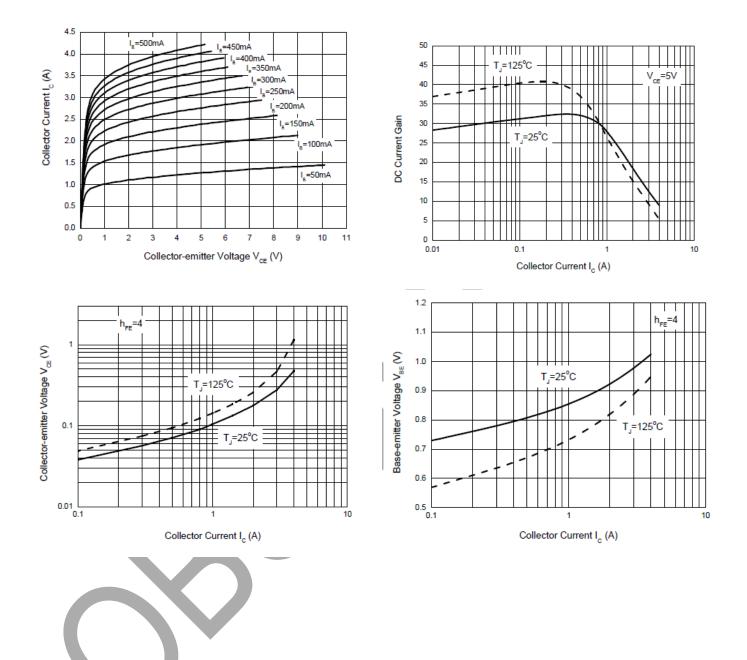
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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV _{CES}	700	—	—	V	$I_{C} = 100 \mu A, V_{BE} = 0 V$
Collector-Emitter Breakdown Voltage	BV _{CEO}	450	—	—	V	I _C = 100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	9	—	—	V	I _E = 100μA
Collector Cutoff Current	I _{CEV}	-	—	10	μA	V _{CE} = 700V, V _{BE} = -1.5V
DC current transfer Static ratio (Note 6)	h	15		35	_	I _C = 1A, V _{CE} = 5V
	h _{FE}	8	—	35	—	I _C = 2A, V _{CE} = 5V
		_	_	0.3		I _C = 1A, I _B = 0.2A
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}	—	—	0.6	V	I _C = 2A, I _B = 0.5A
		_	—	0.9		I _C = 4A, I _B = 1A
Base-Emitter Saturation Voltage (Note 6)	V _{BE(sat)}	_	—	1.1	N	I _C = 1A, I _B = 0.2A
Dase-Emilier Galdralion Voltage (Note 0)	VBE(sat)	_	—	1.3	V	$I_{\rm C} = 2A, I_{\rm B} = 0.5A$
Output Capacitance	Cobo		45	—	pF	V_{CB} = 10V, f = 0.1MHz
Transition Frequency	f _T	4	—	_	MHz	I _C = 0.5A, V _{CE} = 10V
Turn-on Time with Resistive Load	t _{on}	_	_	0.7		
Storage Time with Resistive Load	ts	_	—	4.0	μs	$I_{C} = 2A, V_{CC} = 125V$ $I_{B1} = -I_{B2} = 0.4A$
Fall Time with Resistive Load	t _f	_	-	0.8		1B11B2 - 0.4A

APT13005DI-G1 Diodes Incorporated TRANS NPN 450V 4A TO251

Note: 6. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

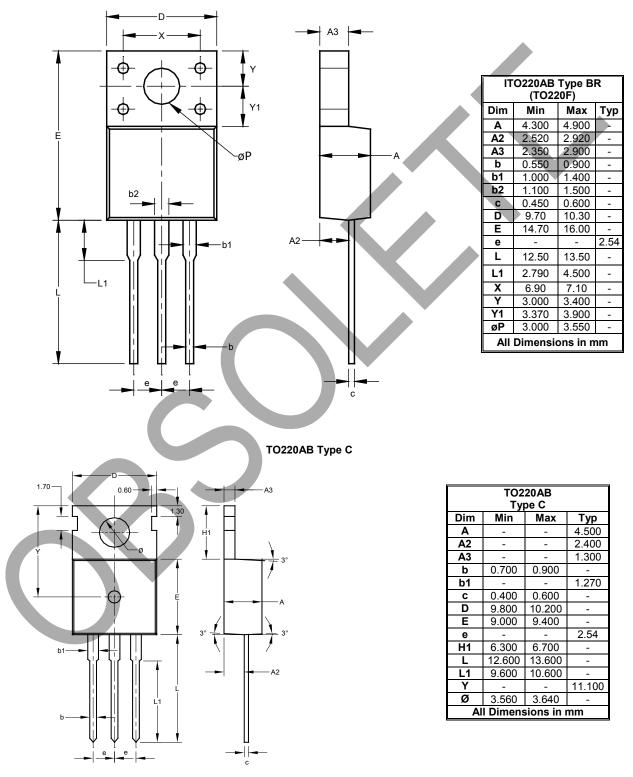




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

ITO220AB Type BR (TO220F)





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